## H11F1M, H11F2M, H11F3M Photo FET Optocouplers

## Features

As a remote variable resistor:
$\square \leq 100 \Omega$ to $\geq 300 \mathrm{M} \Omega$

- $\geq 99.9 \%$ linearity
$\square \leq 15 \mathrm{pF}$ shunt capacitance
$\square \geq 100 \mathrm{G} \Omega \mathrm{I} / \mathrm{O}$ isolation resistance
As an analog switch:
■ Extremely low offset voltage
■ $60 \mathrm{~V}_{\mathrm{pk}-\mathrm{pk}}$ signal capability
■ No charge injection or latch-up
- $\mathrm{t}_{\text {on }}, \mathrm{t}_{\text {off }} \leq 15 \mu \mathrm{~S}$

■ UL recognized (File \#E90700)

## Applications

As a remote variable resistor:

- Isolated variable attenuator
- Automatic gain control
- Active filter fine tuning/band switching

As an analog switch:

- Isolated sample and hold circuit

■ Multiplexed, optically isolated $A / D$ conversion

## Packages



## General Description

The H11FXM series consists of a Gallium-AluminumArsenide IRED emitting diode coupled to a symmetrical bilateral silicon photo-detector. The detector is electrically isolated from the input and performs like an ideal isolated FET designed for distortion-free control of low level AC and DC analog signals. The H11FXM series devices are mounted in dual in-line packages.

## Schematic



Absolute Maximum Ratings ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise specified)
Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

| Symbol | Parameter | Device | Value | Units |
| :---: | :---: | :---: | :---: | :---: |
| TOTAL DEVICE |  |  |  |  |
| $\mathrm{T}_{\text {STG }}$ | Storage Temperature | All | -55 to +150 | ${ }^{\circ} \mathrm{C}$ |
| ToPR | Operating Temperature | All | -40 to +100 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {SOL }}$ | Lead Solder Temperature | All | 260 for 10 sec | ${ }^{\circ} \mathrm{C}$ |
| EMITTER |  |  |  |  |
| $\mathrm{I}_{\mathrm{F}}$ | Continuous Forward Current | All | 60 | mA |
| $\mathrm{V}_{\mathrm{R}}$ | Reverse Voltage | All | 5 | V |
| $\mathrm{I}_{\mathrm{F}(\mathrm{pk})}$ | Forward Current - Peak (10 $\mu$ s pulse, 1\% duty cycle) | All | 1 | A |
| $\mathrm{P}_{\mathrm{D}}$ | LED Power Dissipation $25^{\circ} \mathrm{C}$ Ambient Derate Linearly from $25^{\circ} \mathrm{C}$ | All | 100 | mW |
|  |  |  | 1.33 | $\mathrm{mW} /{ }^{\circ} \mathrm{C}$ |
| DETECTOR |  |  |  |  |
| $P_{D}$ | Detector Power Dissipation @ $25^{\circ} \mathrm{C}$ | All | 300 | mW |
|  | Derate linearly from $25^{\circ} \mathrm{C}$ |  | 4.0 | $\mathrm{mW} /{ }^{\circ} \mathrm{C}$ |
| $\mathrm{BV}_{4-6}$ | Breakdown Voltage (either polarity) | H11F1M, H11F2M | $\pm 30$ | V |
|  |  | H11F3M | $\pm 15$ | V |
| ${ }_{4-6}$ | Continuous Detector Current (either polarity) | All | $\pm 100$ | mA |

Electrical Characteristics ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise specified.)
Individual Component Characteristics

| Symbol | Parameter | Test Conditions | Device | Min. | Typ.* | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| EMITTER |  |  |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{F}}$ | Input Forward Voltage | $\mathrm{I}_{\mathrm{F}}=16 \mathrm{~mA}$ | All |  | 1.3 | 1.75 | V |
| $\mathrm{I}_{\mathrm{R}}$ | Reverse Leakage Current | $\mathrm{V}_{\mathrm{R}}=5 \mathrm{~V}$ | All |  |  | 10 | $\mu \mathrm{A}$ |
| $\mathrm{C}_{J}$ | Capacitance | $\mathrm{V}=0 \mathrm{~V}, \mathrm{f}=1.0 \mathrm{MHz}$ | All |  | 50 |  | pF |
| OUTPUT DETECTOR |  |  |  |  |  |  |  |
| $\mathrm{BV}_{4-6}$ | Breakdown Voltage Either Polarity | $\mathrm{I}_{4-6}=10 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{F}}=0$ | H11F1M, H11F2M | 30 |  |  | V |
|  |  |  | H11F3M | 15 |  |  |  |
| $1_{4-6}$ | Off-State Dark Current | $\mathrm{V}_{4-6}=15 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=0$ | All |  |  | 50 | nA |
|  |  | $\begin{aligned} & \mathrm{V}_{4-6}=15 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=0, \\ & \mathrm{~T}_{\mathrm{A}}=100^{\circ} \mathrm{C} \end{aligned}$ | All |  |  | 50 | $\mu \mathrm{A}$ |
| $\mathrm{R}_{4-6}$ | Off-State Resistance | $\mathrm{V}_{4-6}=15 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=0$ | All | 300 |  |  | $\mathrm{M} \Omega$ |
| $\mathrm{C}_{4-6}$ | Capacitance | $\begin{aligned} & V_{4-6}=15 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=0, \\ & \mathrm{f}=1 \mathrm{MHz} \end{aligned}$ | All |  |  | 15 | pF |

## Transfer Characteristics

| Symbol | Characteristics | Test Conditions | Device | Min | Typ* | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| DC CHARACTERISTICS |  |  |  |  |  |  |  |
| $\mathrm{R}_{4-6}$ | On-State Resistance | $\begin{aligned} & I_{F}=16 \mathrm{~mA}, \\ & I_{4-6}=100 \mu \mathrm{~A} \end{aligned}$ | H11F1M |  |  | 200 | $\Omega$ |
|  |  |  | H11F2M |  |  | 330 |  |
|  |  |  | H11F3M |  |  | 470 |  |
| $\mathrm{R}_{6-4}$ | On-State Resistance | $\begin{aligned} & I_{F}=16 \mathrm{~mA}, \\ & I_{6-4}=100 \mu \mathrm{~A} \end{aligned}$ | H11F1M |  |  | 200 | $\Omega$ |
|  |  |  | H11F2M |  |  | 330 |  |
|  |  |  | H11F3M |  |  | 470 |  |
|  | Resistance, non-linearity and assymetry | $\begin{aligned} & I_{F}=16 \mathrm{~mA}, \\ & \mathrm{I}_{4-6}=25 \mu \mathrm{~A} M \mathrm{RM}, \\ & \mathrm{f}=1 \mathrm{kHz} \end{aligned}$ | All |  |  | 0.1 | \% |
| AC CHARACTERISTICS |  |  |  |  |  |  |  |
| $\mathrm{t}_{\text {on }}$ | Turn-On Time | $\begin{aligned} & R_{\mathrm{L}}=50 \Omega, \mathrm{I}_{\mathrm{F}}=16 \mathrm{~mA}, \\ & \mathrm{~V}_{4-6}=5 \mathrm{~V} \end{aligned}$ | All |  |  | 25 | $\mu \mathrm{S}$ |
| $\mathrm{t}_{\text {off }}$ | Turn-Off Time | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{I}_{\mathrm{F}}=16 \mathrm{~mA}, \\ & \mathrm{~V}_{4-6}=5 \mathrm{~V} \end{aligned}$ | All |  |  | 25 | $\mu \mathrm{S}$ |

## Isolation Characteristics

| Symbol | Characteristic | Test Conditions | Device | Min. | Typ. | Max. | Units |
| :---: | :--- | :--- | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {ISO }}$ | Isolation Voltage | $\mathrm{f}=60 \mathrm{~Hz}, \mathrm{t}=1$ sec. | All | 7500 |  |  | $\mathrm{~V}_{\mathrm{AC}} \mathrm{PEAK}$ |
| $\mathrm{R}_{\mathrm{ISO}}$ | Isolation Resistance | $\mathrm{V}_{\mathrm{I}-\mathrm{O}}=500 \mathrm{VDC}$ | All | $10^{11}$ |  |  | $\Omega$ |
| $\mathrm{C}_{\text {ISO }}$ | Isolation Capacitance | $\mathrm{f}=1 \mathrm{MHz}$ | All |  | 0.2 |  | pF |

*All Typical values at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$

Typical Performance Curves

Figure 1. Resistance vs. Input Current


Figure 3. LED Forward Voltage vs. Forward Current


Figure 5. Resistance vs. Temperature


Figure 2. Output Characteristics


Figure 4. Off-state Current vs. Ambient Temperature


Figure 6. Region of Linear Resistance


Figure 7. Resistive non-linearity vs. D.C. Bias


## Typical Applications

## As a Variable Resistor <br> ISOLATED VARIABLE ATTENUATORS



LOW FREQUENCY
@10KHz DYNAMIC RANGE 70db


HIGH FREQUENCY @1MHz $\underset{\text { FOR } 0 \leq I_{F} \leq 30 \mathrm{~mA}}{\text { DYNAMIC RANGE }}$ 50db

Distortion free attenuation of low level A.C. signals is accomplished by varying the IRED current, $I_{F}$ Note the wide dynamic range and absence of coupling capacitors; D.C. level shifting or parasitic feedback to the controlling function.

AUTOMATIC GAIN CONTROL


This simple circuit provides over 70db of stable gain control for an AGC signal range of from 0 to 30 mA . This basic circuit can be used to provide programmable fade and attack for electronic music.

ACTIVE FILTER FINE TUNING/BAND SWITCHING


The linearity of resistance and the low offset voltage of the H11FXM allows the remote tuning or band-switching of active filters without switching glitches or distortion. This schematic illustrates the concept, with current to the H11F1M IRED's controlling the filter's transfer characteristic.

## As an Analog Signal Switch

ISOLATED SAMPLE AND HOLD CIRCUIT


Accuracy and range are improved over conventional FET switches because the H11FXM has no charge injection from the control signal. The H11FXM also provides switching of either polarity input signal up to 30 V magnitude.

MULTIPLEXED, OPTICALLY-ISOLATED A/D CONVERSION


The optical isolation, linearity and low offset voltage of the H11FXM allows the remote multiplexing of low level analog signals from such transducers as thermocouplers, Hall effect devices, strain gauges, etc. to a single A/D converter.

TEST EQUIPMENT - KELVIN CONTACT POLARITY


In many test equipment designs the auto polarity function uses reed relay contacts to switch the Kelvin Contact polarity. These reeds are normally one of the highest maintenance cost items due to sticking contacts and mechanical problems. The totally solid-State H11FXM eliminates these troubles while providing faster switching.

## Package Dimensions

Through Hole

0.4" Lead Spacing


Note:
All dimensions are in inches (millimeters).

Surface Mount


Recommended Pad Layout for Surface Mount Leadform


Ordering Information

| Option | Order Entry Identifier <br> (Example) | Description |
| :---: | :---: | :--- |
| No option | H11F1M | Standard Through Hole Device |
| S | H11F1SM | Surface Mount Lead Bend |
| SR2 | H11F1SR2M | Surface Mount; Tape and Reel |
| T | H11F1TM | $0.4 "$ Lead Spacing |
| V | H11F1TVM | VDE 0884 |
| TV | H11F1SVM | VDE 0884, 0.4" Lead Spacing |
| SV | H11F1SR2VM | VDE 0884, Surface Mount, Tape and Reel |
| SR2V |  |  |


| Definitions |  |
| :---: | :--- |
| 1 | Fairchild logo |
| 2 | Device number |
| 3 | VDE mark (Note: Only appears on parts ordered with VDE <br> option - See order entry table) |
| 4 | One digit year code, e.g., '7' |
| 5 | Two digit work week ranging from '01' to ‘53' |
| 6 | Assembly package code |

## Carrier Tape Specifications



## Reflow Profile



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| FPS ${ }^{\text {™ }}$ | PDP-SPM ${ }^{\text {TM }}$ | SuperFET ${ }^{\text {TM }}$ | UHC ${ }^{\circledR}$ |
| FRFET ${ }^{\circledR}$ | Power220 ${ }^{\text {® }}$ | SuperSOT ${ }^{\text {TM }}$-3 | UniFET ${ }^{\text {тм }}$ |
| Global Power Resource ${ }^{\text {SM }}$ | Power247 ${ }^{\circledR}$ | SuperSOT ${ }^{\text {TM }}$-6 | VCX ${ }^{\text {TM }}$ |
| Green FPS ${ }^{\text {™ }}$ | POWEREDGE ${ }^{\circledR}$ | SuperSOT ${ }^{\text {TM }}$-8 | VCX |

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